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Version 1.2, Aug 2004

Datasheet

DS-CoreControl-TDA21107

TDA21107

Published by Infineon Technologies AG
http://www.infineon.com/DCDC

Power Management & Drive

Never stop thinking.

Contents:

High speed Driver with bootstrapping for dual Power MOSFETs

P-DSO-8

Features:

- Fast rise and fall times for frequencies up to 1 MHz
- Adjustable High Side MOSFET gate drive voltage via external voltage supply to BOOT for optimizing ON losses and gate drive losses (5V to 12V is recommended)
- Prevents from cross-conducting by adaptive gate drive control
- Supports shut-down mode for very low quiescent current through three-state input
- Compatible to standard PWM controller ICs (IFX, Intersil, Analog Devices, Richtek)
- Floating High Side MOSFET drive
- Power-on Overvoltage Protection
- Footprint compatible to ADP3418
- Ideal for multi-phase Desktop CPU supplies on motherboards and VRM´s

Application:

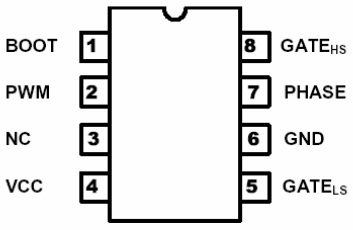
- Voltage Regulator Modules
- Low Output Voltage High Output Current DC-DC Converters
- Half-Bridge Class D Amplifier

Type	Package	Marking	Ordering Code
TDA21107	P-DSOP-8	21107	Q67042-S4251

Pinout Drawing and Description:

Pinout

Top View



Number	Name	Description
1	BOOT	Floating bootstrap pin. To be connected to the external bootstrap capacitor to generate the gate drive voltage for the high side N-Channel MOSFET
2	PWM	Input for the PWM signal from controller
3	NC	No Connection
4	VCC	Supply voltage
5	GATE$_{LS}$	Gate drive output for the N-Channel Low Side MOSFET
6	GND	Ground
7	PHASE	To be connected to the junction of the High Side and the Low Side MOSFET
8	GATE$_{HS}$	Gate drive output for the N-Channel High side MOSFET

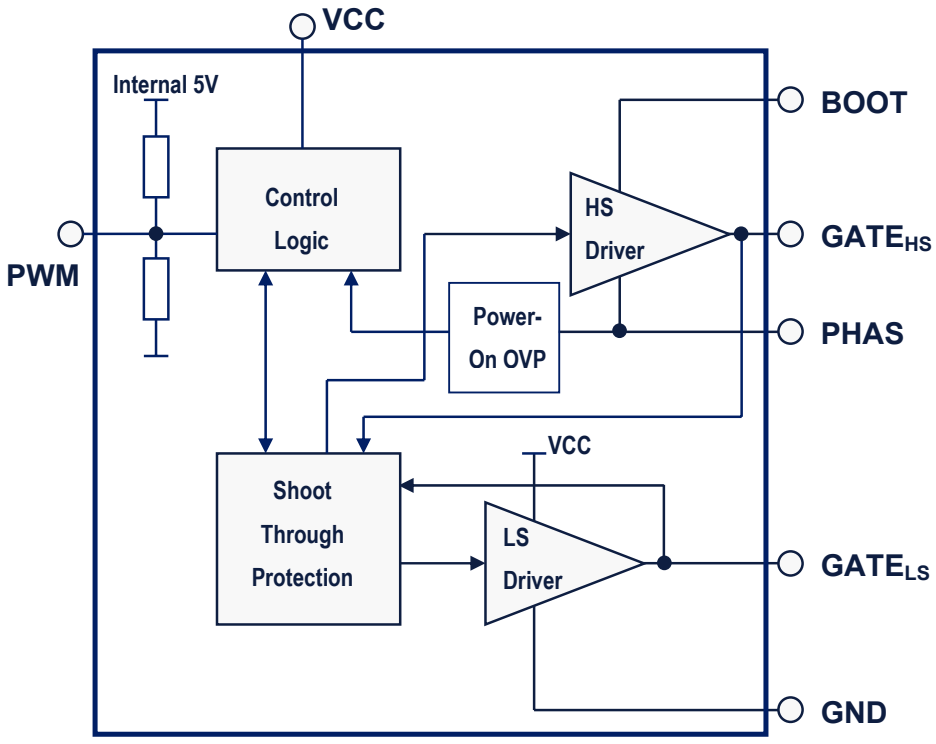
General Description

The dual high speed driver is designed to drive a wide range of N-Channel low side and N-Channel high side MOSFETs with varying gate charges. It has a small propagation delay from PWM input pin to $GATE_{HS}$ and $GATE_{LS}$, short rise and fall times and the same pin configuration as the ADP3418. In addition it provides several protection features as well as a shut down mode for efficiency reasons.

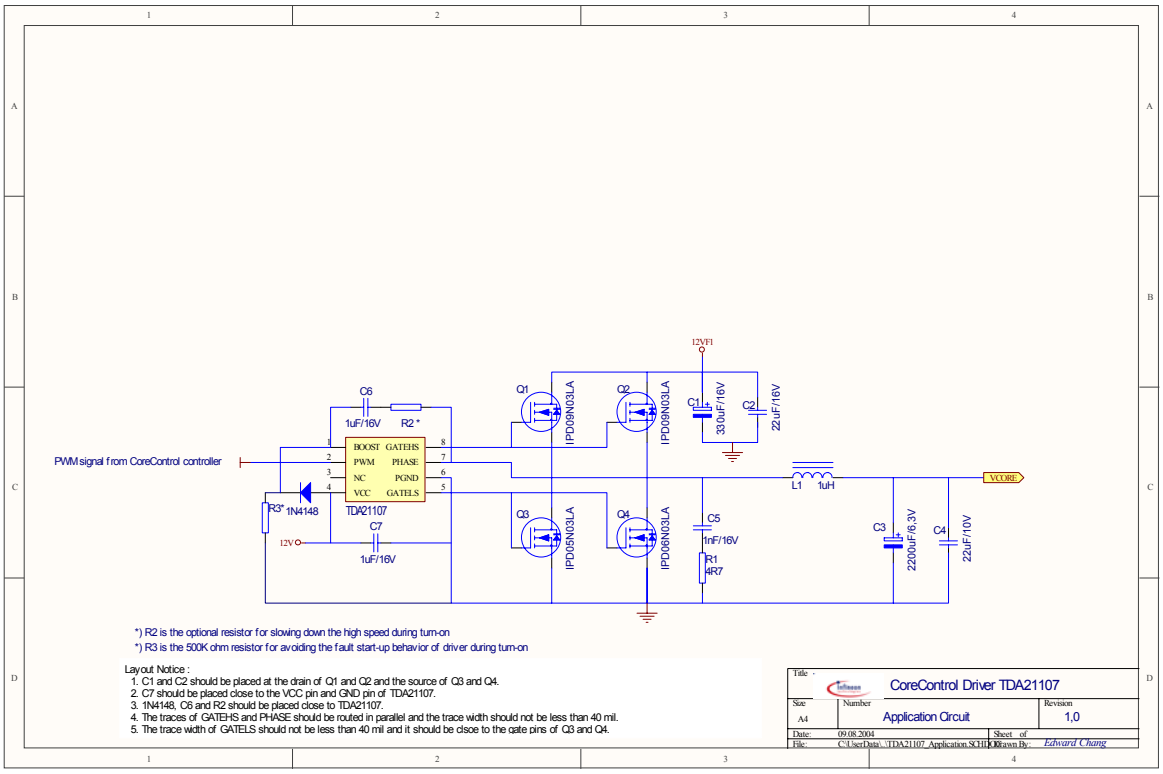
Target application

The dual high speed driver is designed to work well in half-bridge type circuits where dual N-Channel MOSFETs are utilized. A circuit designer can fully take advantage of the driver´s capabilities in high-efficiency, high-density synchronous DC/DC converters that operate at high switching frequencies, e.g. in multi-phase converters for CPU supplies on motherboards and VRM´s but also in motor drive and half bridge class-D amplifier type applications.

Block Diagram



Application Circuit



Absolute Maximum Ratings

At Tj = 25 °C, unless otherwise specified

Parameter	Symbol	Value		Unit
		Min	MAX	
Voltage supplied to 'VCC' pin; DC	V_{VCC}	-0.3	15	V
Voltage supplied to 'PWM' pin	V_{PWM}	-0.3	7	
Voltage supplied to 'BOOT' pin referenced to 'PHASE'	$V_{BOOT} - V_{PHASE}$	-0.3	15	
Voltage supplied to 'BOOT' pin referenced to 'GND'	V_{BOOT}	-0.3	30	
Voltage rating at 'PHASE' pin,	V_{PHASE}	-4	15	
Voltage supplied to $GATE_{HS}$ pin referenced to 'PHASE	V_{GATEHS}	V_{PHASE} - 0.3	V_{BOOT} +0.3	
Voltage supplied to $GATE_{LS}$ pin referenced to 'GND'	V_{GATELS}	-0.3	V_{VCC} +0.3	
Junction temperature	T_J	0	150	°C
Storage temperature	T_S	-40	150	
Lead temperature (Soldering, 10 seconds)			260	
ESD Rating; Human Body Model			2	KV
Machine Mode			200	V
IEC climatic category; DIN EN 60068-1	55/150/56			

Thermal Characteristic

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal resistance, junction-soldering point			90		K/W
Thermal resistance, junction-ambient			125		

Operating Conditions

At Tj = 25 °C, unless otherwise specified

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Voltage supplied to 'VCC' pins	V_{VCC}		10.8	12.0	13.2	V
Input signal transition frequency	f		50		500	KHz
Power dissipation	P_{TOT}	T_A = 25 °C, T_J = 125 °C		0.8		W
Junction temperature	T_J		0		125	°C
Ambient temperature	T_A		0		70	°C

Electrical Characteristic

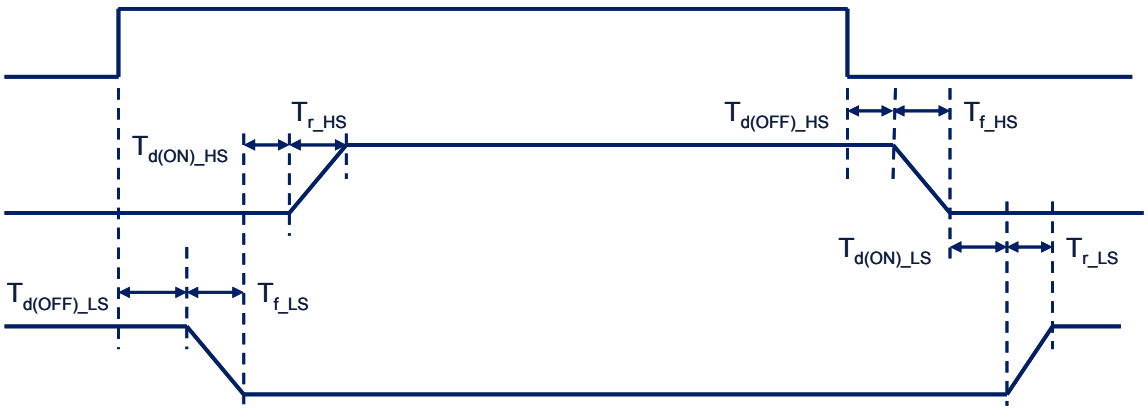
At Tj = 25 °C, unless otherwise specified

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Supply Characteristic						
VCC supply current	I_{VCC}	V_{VCC} = 12 V V_{PWM} = 0V		5	7	mA
Under-voltage lockout		V_{VCC} rising threshold	8.6	9.4	10.2	V
Under-voltage lockout		V_{VCC} falling threshold	7.25	8.05	8.85	
Input Characteristic						
Current in 'PWM' pin	I_{PWM_L}	$V_{\_PWM}$ = 0 V	-80	-110	-140	µA
Current in 'PWM' pin	I_{PWM_H}	$V_{\_PWM}$ = 5 V	80	110	140	
PWM pin open	V_{PWM_O}		2.2	2.5	2.8	V
PWM Low level	V_{PWM_L}		1.2	1.4	1.5	
PWM High level	V_{PWM_H}		3.0	3.5	3.8	

At Tj = 25 °C, unless otherwise specified

Dynamic Characteristic						
Turn-on propagation Delay High Side	$t_{d(ON)\_HS}$	P_{PVCC} = V_{VCC}= 12 V C_{ISS} = 3000 pF		40		ns
Turn-off propagation delay High Side	$t_{d(OFF)\_HS}$			30		
Rise time High Side	t_{r_HS}			30		
Fall time High Side	t_{f_HS}			40		
Turn-on propagation Delay Low Side	$t_{d(ON)\_LS}$			35		
Turn-off propagation delay Low Side	$t_{d(OFF)\_LS}$			30		
Rise time Low Side	t_{r_LS}			30		
Fall time Low Side	t_{f_LS}			30		

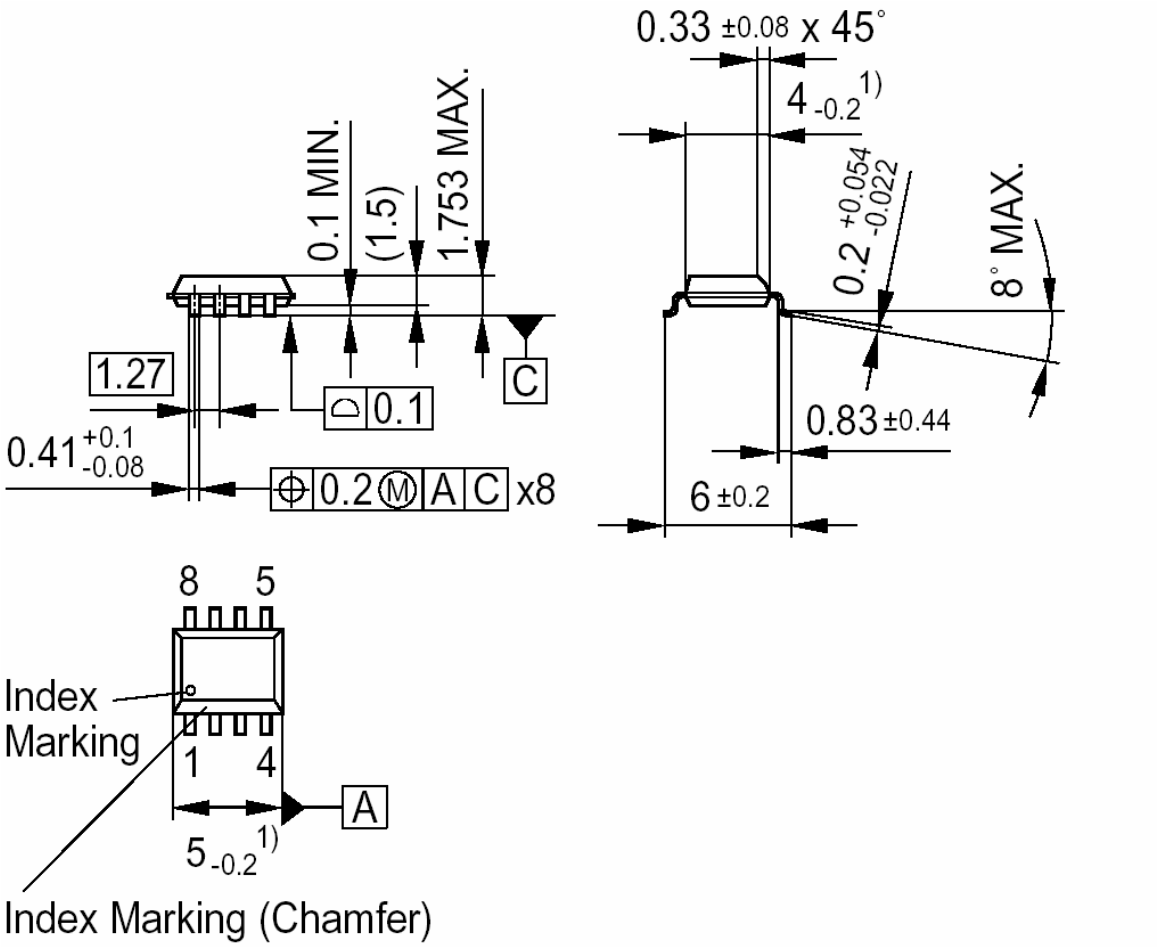
Timing diagram



At Tj = 25 °C, unless otherwise specified

Parameter		Conditions	Values			Unit
			Min.	Typ.	Max.	
Output Characteristic High Side (HS) and Low Side (LS), ensured by design						
Output Reistance	HS; Source	V_{PVCC} = V_{VCC}= 12 V		2		Ω
	HS; Sink			1.5		
	LS; Source			1.6		
	LS; Sink			1.2		

Package Drawing P-DSO-8



1) Does not include plastic or metal protrusion of 0.15 max. per side

Footprint Drawing P-DSO-8

e	A	L	B
1.27 mm	5.69 mm	1.31 mm	0.65 mm

Revision History			
Datasheet DS-CoreControl-TDA21107			
Actual Release: V1.1 Date: 22.03.2005		Previous Release: V1.0	Date: 10.08.2004
Page of actual Rel.	Page of prev. Rel.	Subjects changed since last release	
9	9	Add $t_{d(OFF)\_HS}$ = 30 ns and $t_{d(OFF)\_LS}$ = 30 ns	

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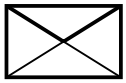

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INFINEON TECHNOLOGIES AG Sales Offices Worldwide *

Austria
Infineon Technologies Austria AG
Operngasse 20b/31
A-1040 Wien
T (+43) 1-58 7-70 70 0
Fax (+43) 1-58 7-70 70 20

Australia
Siemens Ltd.
885 Mountain Highway
Bayswater,Victoria 3153
T (+61) 3-97 21 21 11
Fax (+61) 3-97 21 72 75

Belgium/Netherlands
Infineon Technologies Holding B.V.
Sales Division
Westblaak 32
3012 KM Rotterdam
T (+31) 10 -2 17 68 00
Fax (+31) 10 -2 17 68 19

Brazil
Infineon Technologies
South America Ltda.
Avenida Mutinga,3800-Prédio 3
05110-901 São Paulo-SP
T (+55) 11-39 08 25 64
Fax (+55) 11-39 08 27 28

Canada
Infineon Technologies Corporation
340 March Road,Suite 301
Canada,Ontario K2K 2E2
T (+1) 6 13-5 91 38 35
Fax (+1) 6 13-5 91 89 54

China
Infineon Technologies International Trade (Shanghai) Co., Ltd
Beijing Representative Office
12th Floor, Quantum Plaza
No.27 Zhichun Road, Haidian Distric,
Beijing 100083,
People's Republic of China
T (+86) 10 82 35 61 18
Fax (+86) 10 82 35 54 74

Infineon Technologies Hong Kong Ltd, Hong Kong Office
302 Level 3 Festival Walk 80 Tat Chee Avenue, Kowloon Tong
Hong Kong
T (+852) 28 32 05 00
Fax (+852) 28 27 97 62

Infineon Technologies International Trade (Shanghai) Co., Ltd
No.8, Lane 647, Songtao Road
Zhangjiang Hi-Tech Park
Pudong, Shanghai, China

Infineon Technologies International Trade (Shanghai) Co., Ltd
Shenzhen Office
Room 1501-05, Block A
Tian An International Building
Renmin Nan Road
Shenzhen 518001, China
T (+86) 7 55 -2 28 91 04
Fax (+86) 7 55 -2 28 02 17

Germany
Infineon Technologies AG
Siemensstraße 31-33
71254 Ditzingen/Stuttgart
T (+49) 71 56 -1 79 19 10
Fax (+49) 71 56 -1 79 19 90

Infineon Technologies AG
Völklinger Straße 4
40219 Düsseldort
T (+49) 2 11 -20 95 49 0
Fax (+49) 2 11 -20 95 49 60

Infineon Technologies AG
Naegelsbachstraße 26
91052 Erlangen
T (+49) 91 31 97 00 10
Fax (+49) 91 31 97 00 99

Infineon Technologies AG
Paderborner Straße 1
30539 Hannover
T (+49) 5 11 87 65 62 0
Fax (+49) 5 11 87 65 62 90

Infineon Technologies AG
Rosenheimer Straße 116
81669 München
T (+49) 89 23 40
Fax (+49) 89 23 42 46 94

Infineon Technologies AG
Südwestpark 65
90449 Nürnberg
T (+49) 9 11 -2 52 93 0
Fax (+49) 9 11 -2 52 93 93

Denmark
Infineon Technologies Nordic A/S
Herlev Hovedgade 201A
DK 2730 Herlev
T (+45) 44 50 77 00
Fax (+45) 44 50 77 01

Finland
Infineon Technologies Nordic OY
Linnouitustie 4A
P.O. BOX 276
FIN-02601 Espoo
T (+3 58) 10 -6 80 84 00
Fax (+3 58) 10 -6 80 84 01

France
Infineon Technologies France SAS
39 – 47, Bd. Ornano
93527 Saint-Denis CEDEX2
T (+33) 1 48 09 72 00
Fax (+33) 1 48 09 72 90

India
Infineon Technologies India Pvt. Ltd.
10th Floor, Discoverer Building
International Technology Park
Whitefield Road
Bangalore 560 066, India
T (+91) 80 8 41 00 17/18
Fax (+91) 80 8 41 00 12

Ireland
Infineon Technologies Ireland Ltd.
69 Fitzwilliam Lane
Dublin 2, Ireland
T (+35) 31 79 99 500
Fax (+35) 31 79 99 501

Israel
Nisko Ltd.
2A, Habarzel Street
Tel Aviv 69710, Isreal
T (+9 72)3 -7 65 73 00
Fax (+9 72)3 -7 65 73 33

Italy
Infineon Technologies Italy S.r.l.
Via Vipiteno 4
20128 Milano, Italy
T (+39) 022 52 04 1
Fax (+39) 022 52 04 43 95

Japan
Infineon Technologies Japan K.K.
Takanawa Park Tower 8F/9f/12F/17F
3-20-14, Higashi-Gotanda
Shinagawa-ku
Tokyo 141-0022, Japan
T (+81) 3 54 49 64 11
Fax (+81) 3 54 49 64 01

Korea
Infineon Technologies Korea Co., Ltd..
Room No. 2&3,9th floor
Daelim Acrotel Building
467-6 Dokock-Dong. Kangnam-Gu
Seoul, Korea 135-971
T (+82) 23 46 00 900
Fax (+82) 23 46 00 901/902

Malaysia
Infineon Technologies (M) SDN BHD
Krystal Point II
1-4-11/12, Lebuh Bukit Kecil 6
11900 Bayan Lepas
Penang, Malaysia
T (+60) 46 44 77 66
Fax (+60) 46 41 48 72

New Zeland
Siemens Components
300 Great South Road
Greenland, Auckland
T (+64) 95 20 30 33
Fax (+64) 95 20 15 56

Portugal
Siemens S.A.
OG Componentes Electronicos
Rua Irmaos Siemens,1
Alfragide
2720-093 Amadora
T (+351) 21-4 17 85 90
Fax (+351) 21-4 17 80 83

Russia
INTECH electronics
ul.Smolnaya,24/1203
125 445 Moskva, Russia
T (+70) 95 -4 51 97 37
Fax (+70) 95 -4 51 86 08

Singapore
Infineon Technologies Asia Pacific Pte. Ltd.
8 Kallang Sector
349282, Singapore
T (+65) 68 40 08 88
Fax (+65) 68 40 xx xx

South Africa
Siemens Components
P.O. Box 3438
Halfway House 1685
Gauteng, South Africa
T (+27) 11 6 52 20 00
Fax (+27) 11 6 52 26 73

Spain
Siemens S.A.
Division Components
Ronda de Europa, 5
28760 Tres Cantos-Madrid
T (+34) 91 5 14 71 54
Fax (+34) 91 5 14 70 13

Sweden
Infineon Technologies Nordic AB
P.O. Box 46
16493 Kista, Sweden
T (+46) 8 7 03 59 00
Fax (+46) 8 7 03 59 01

Switzerland
Infineon Technologies Switzerland AG
Badenerstraße 623
P.O. Box 1570
8048 Zürich
T (+41) 1 4 97 80 40
Fax (+41) 1 4 97 80 50

Taiwan
Infineon Technologies Taiwan.Ltd.
12F-1, No.3-2 Yuan Qu. St., Nan Kang Software Park, Taipei
Taiwan 115, ROC
T (+8 86)2-2655 7500
Fax (+8 86)2-2655 7501-8

Turkey
Siemens Sanayi ve Ticaret A.S.
Yakacik Yolu No.111
34861 Kartal, Istanbul
T (+90) 21 64 59 28 51
Fax (+90) 21 64 19 31 90

United Kindom
Infineon Technologies UK.Ltd.
Infineon House
Fleet Mill
Minley Road
Fleet, Hampshire GU51 2RD
T (+44) 12 52 77 22 00
Fax (+44) 12 52 77 22 01

USA
Infineon Technologies
North America Corporation
3700 West Parmer Lane, Suite 102
Austin, TX 78727
T (+1) 51 23 41 71 27
Fax (+1) 51 23 41 99 26

Infineon Technologies
North America Corporation
8203 Willow Place South, Suite 660
Houston, TX 77070
T (+1) 28 17 74 05 55
Fax (+1) 28 17 74 05 61

Infineon Technologies
North America Corporation
485 Route 1 South
Iselin, NJ 08830
T (+1) 73 28 55 92 00
Fax (+1) 73 28 55 92

Infineon Technologies
North America Corporation
2529 Commerce Drive
Kokomo, IN 46902
T (+1) 7 65 -4 56 19 28
Fax (+1) 7 65 -4 56 38 36

Eupec Inc.
1050 Route 22
Lebanob, NJ 08833
T (+1) 90 8 -2 36 56 21
Fax (+1) 90 8 -2 36 56 20

Infineon Technologies
North America Corporation
21800 Haggerty Road, Suite 112
Northville, MI 48167
T (+1) 2 48 -3 74 08 90
Fax (+1) 2 48 -3 74 25 01

Infineon Technologies
North America Corporation
2901 Dallas N. Tollway, Suite 370
Plano, TX 75093
T (+1) 97 23 78 49 46
Fax (+1) 97 24 03 97 89

Infineon Technologies
North America Corporation
3000 CentreGreen Way
Raleigh, NC 27513
T (+1) 91 96 77 27 00
Fax (+1) 91 96 78 19 34

Infineon Technologies
North America Corporation
6170 Cornerstone Ct East, Suite 240
San Diego, CA 92121
T (+1) 85 85 26 22 01
Fax (+1) 85 85 26 22 02

Infineon Technologies Corporation
1730 North First Street
San Jose, CA 95112
T (+1)4 08 -5 01 60 00
Fax (+1)4 08 -5 01 24 24

Infineon Technologies
North America Corporation
1901 N. Roselle Road, Suite 1020
Schaumburg, IL 60195
T (+1) 84 78 84 70 09
Fax (+1) 84 78 84 75 99

Infineon Technologies
North America Corporation
238 Littleton Road, Suite 200
Westford, MA 01886
T (+1) 97 86 92 05 50
Fax (+1) 97 86 92 23 0

* and representative offices